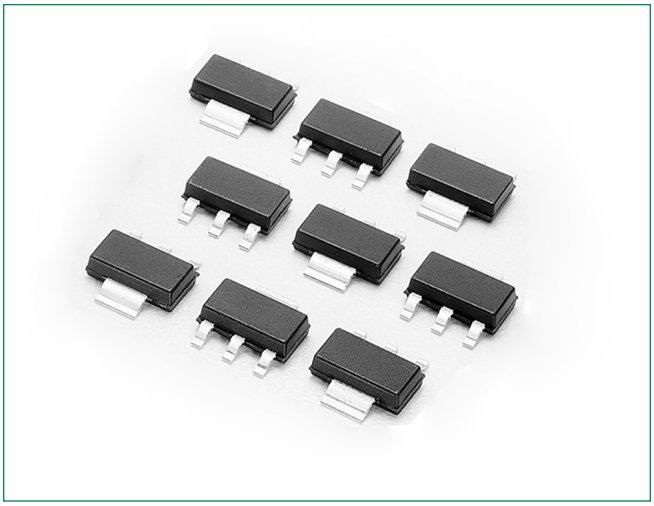
MAC08BT1, MAC08MT1



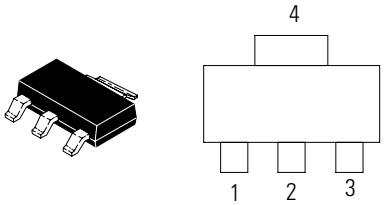
Description

Designed for high volume, low cost, industrial and consumer applications such as motor control; process control; temperature, light and speed control.

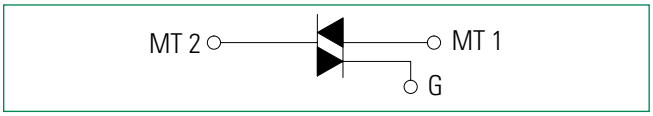
Features

- Sensitive Gate Trigger Current in Four Trigger Modes
- Blocking Voltage to 600 Volts
- Glass Passivated Surface for Reliability and Uniformity
- Surface Mount Package
- Pb–Free Packages are Available

Pin Out



Functional Diagram



Additional Information

Datasheet | Resources | Samples

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Maximum Ratings (T_J = 25°C unless otherwise noted)

Rating		Symbol	Value	Unit
Peak Repetitive Off-State Voltage (Note 1) (Gate Open, Sine Wave 50 to 60 Hz, T_J = -40° to 110°C)	MAC08BT1 MAC08MT1	V_{DRM}, V_{RRM}	200 600	V
On-State RMS Current (Full Cycle Sine Wave, 60 Hz, T_C = 80°C)		$I_{T\ (RMS)}$	0.8	A
Peak Non-Repetitive Surge Current (One Full Cycle Sine Wave, 60 Hz, T_C= 25°C)		I_{TSM}	8.0	A
Circuit Fusing Consideration (t = 8.3 msec)		I^2t	0.4	A^2sec
Peak Gate Power (Pulse Width ≤ 10 µsec, T_C= 80°C)		P_{GM}	5.0	W
Average Gate Power (t = 8.3 msec, T_C= 80°C)		$P_{G(AV)}$	0.1	W
Operating Junction Temperature Range		T_J	-40 to +110	°C
Storage Temperature Range		T_{stg}	-40 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. V_{DRM} and V_{RRM} for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

Thermal Characteristics

Rating	Symbol	Value	Unit
Thermal Resistance, Junction–to–Ambient PCB Mounted per Figure 1	$R_{\theta JA}$	156	°C/W

2. These ratings are applicable when surface mounted on the minimum pad sizes recommended.
3. 1/8" from case for 10 seconds.

Electrical Characteristics - OFF (T_C = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Typ	Max	Unit
†Peak Repetitive Blocking Current (V_{AK} = V_{DRM} = V_{RRM}; Gate Open)	T_J = 25°C	I_{DRM}, I_{RRM}	-	-	10	µA
	T_J = 110°C		-	-	200	mA

Electrical Characteristics - ON (T_C = 25°C unless otherwise noted; Electricals apply in both directions)

Characteristic	Symbol	Min	Typ	Max	Unit
Peak On–State Voltage (Note 2) (I_{TM} = ±1.1 A)	V_{TM}	–	–	1.9	V
Gate Trigger Current (Continuous dc) (V_D = 12 V, R_L = 100 Ω)	I_{GT}	–	–	10	mA
Holding Current (V_D = 12 V, Gate Open, Initiating Current = ±20 mA))	I_H	–	–	5.0	mA
Gate Trigger Voltage (Continuous dc) (V_D = 12 V, R_L = 100 Ω)	V_{GT}	–	–	2.0	V

2. Pulse Test: Pulse Width ≤ 2.0 ms, Duty Cycle ≤ 2%.

Dynamic Characteristics

Characteristic	Symbol	Min	Typ	Max	Unit
Critical Rate of Rise of Commutation Voltage (f = 250 Hz, I_{TM} = 1.0 A, Commutating di/dt = 1.5 A/mS On–State Current Duration = 2.0 mS, V_{DRM} = 200 V, Gate Unenergized, T_C = 110°C, Gate Source Resistance = 150 Ω, See Figure 10)	(dI/dt)c	1.5	–	–	A/ms
Critical Rate of Rise of Off-State Voltage (V_D = 0.67 x V_{DRM}, Exponential Waveform, Gate Open, T_J = 110°C)	dV/dt	10	–	–	V/µs

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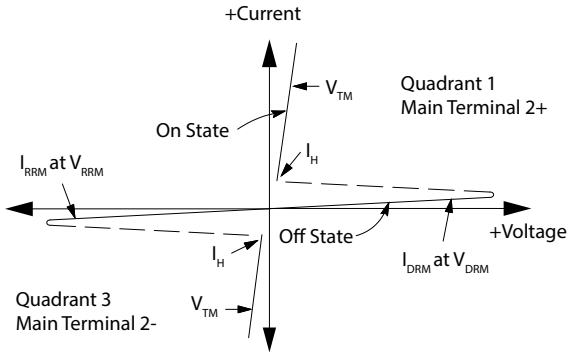
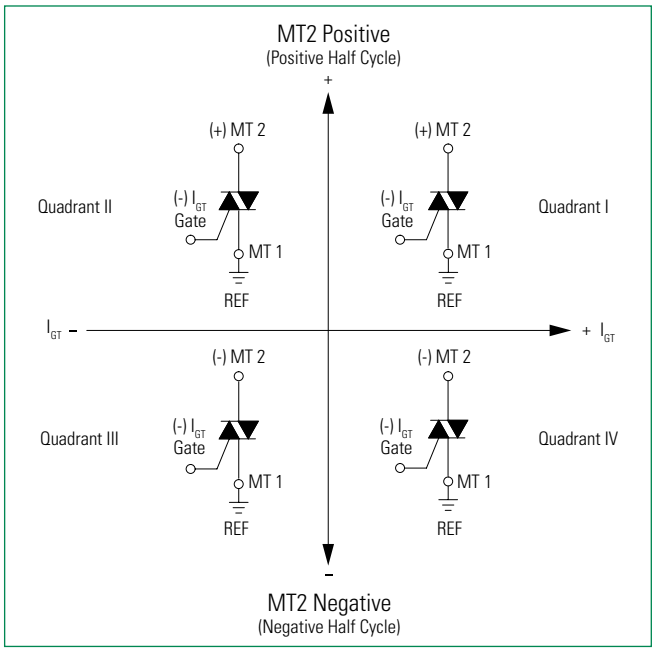
Voltage Current Characteristic of SCR

Symbol	Parameter
V_{DRM}	Peak Repetitive Forward Off State Voltage
I_{DRM}	Peak Forward Blocking Current
V_{RRM}	Peak Repetitive Reverse Off State Voltage
I_{RRM}	Peak Reverse Blocking Current
V_{TM}	Maximum On State Voltage
I_H	Holding Current

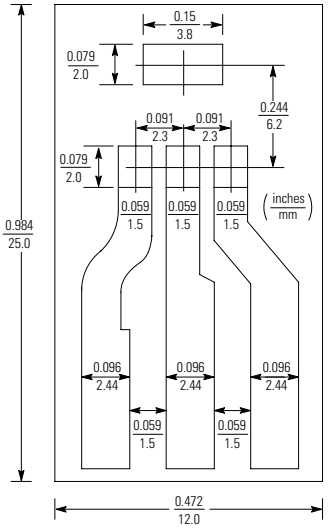


Quadrant Definitions for a Triac



All Polarities are referenced to MT1.
With in-phase signals (using standard AC lines) quadrants I and III are used

Figure 1. PCB for Thermal Impedance and Power Testing of SOT-223



BOARD MOUNTED VERTICALLY IN CINCH 8840 EDGE CONNECTOR.
BOARD THICKNESS = 65 MIL., FOIL THICKNESS = 2.5 MIL.
MATERIAL: G10 FIBERGLASS BASE EPOXY

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Figure 2. On-State Characteristics

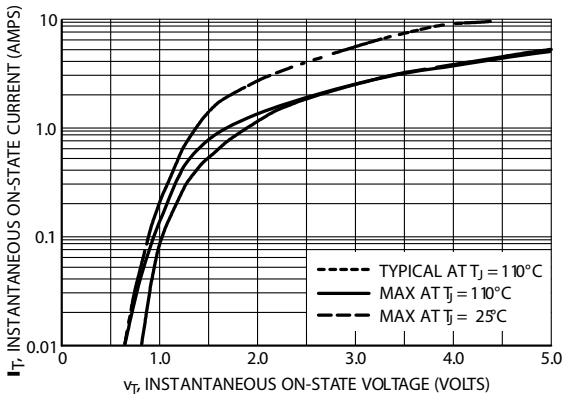

Figure 3. Junction to Ambient Thermal Resistance vs. Copper Tab Area

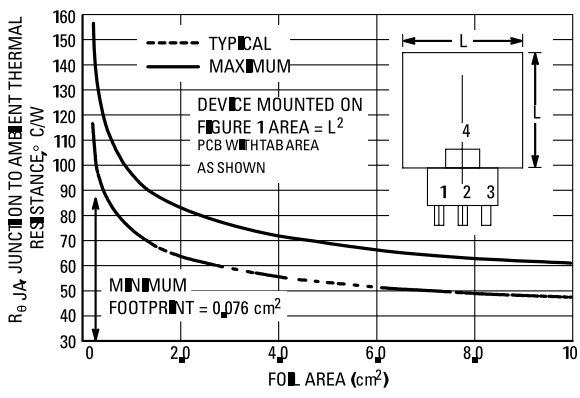

Figure 4. Current Derating, Minimum Pad Size Reference: Ambient Temperature

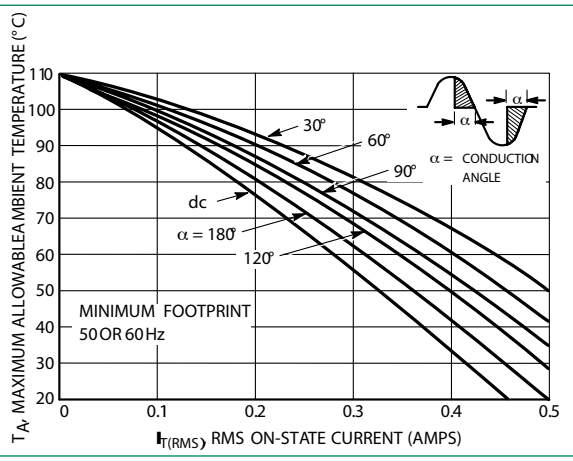

Figure 5. Current Derating, 1.0 cm Square Pad Reference: Ambient Temperature

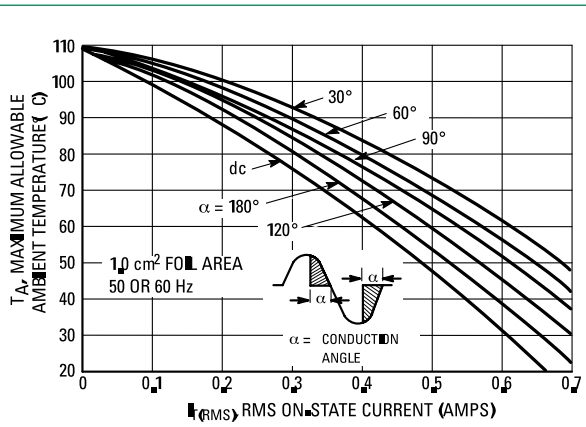

Figure 6. Current Derating, 2.0 cm Square Pad Reference: Ambient Temperature

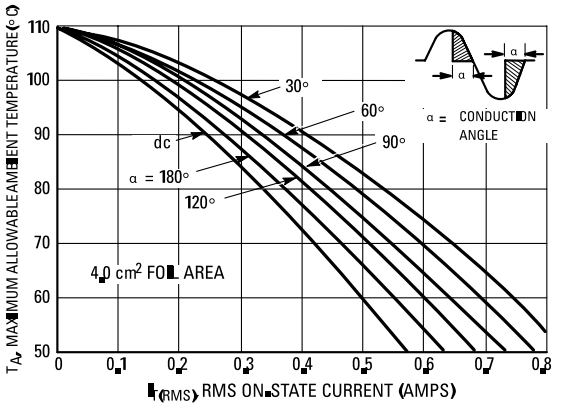

Figure 7. Current Derating Reference: MT2 Tab

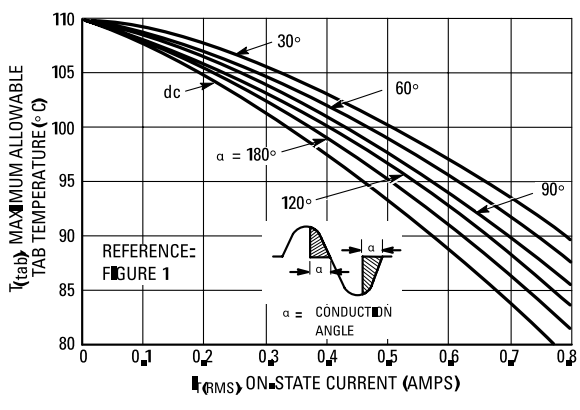

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Figure 8. Power Dissipation

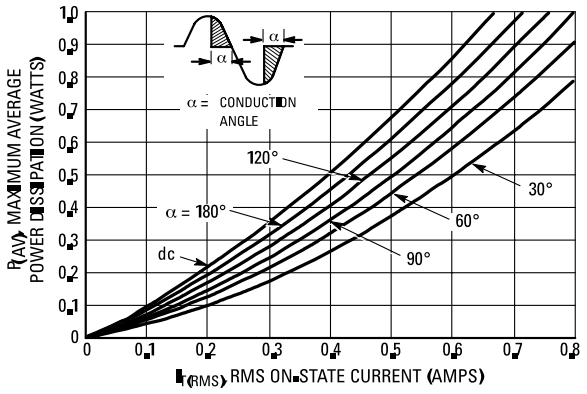


Figure 9. Thermal Response, Device Mounted on Figure 1 Printed Circuit Board

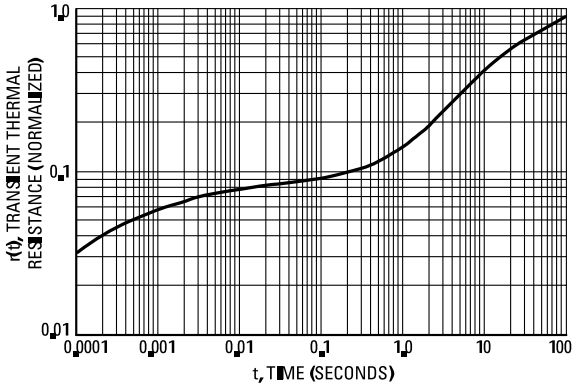
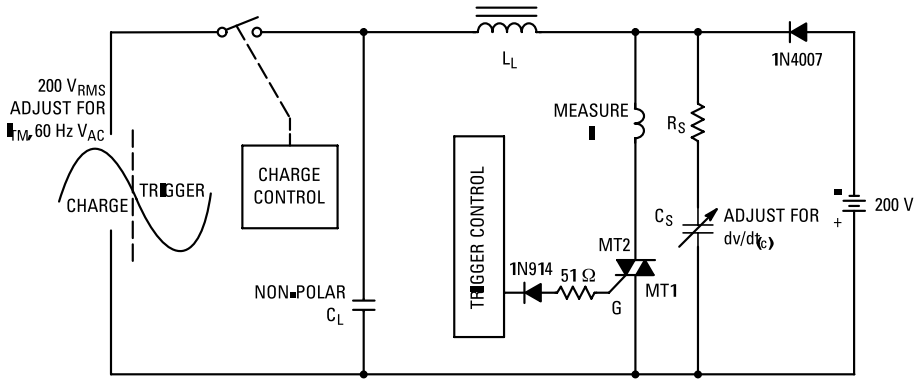


Figure 10. Simplified Test Circuit to Measure the Critical Rate of Rise of Commutating Current (di/dt)



Note: Component values are for verification of rated (dv/dt)c. See AN1048 for additional information.

Figure 11. Typical Commutating dv/dt versus Current Crossing Rate and Junction Temperature

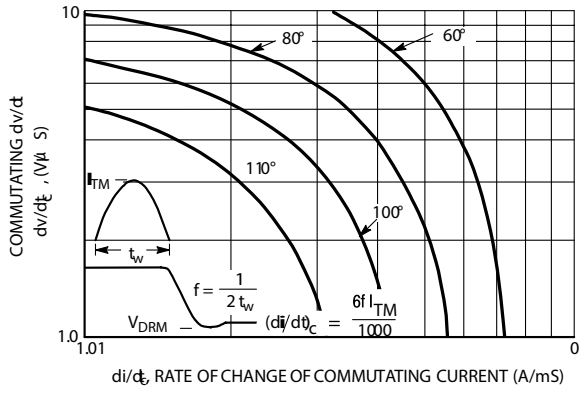


Figure 12. Typical Commutating dv/dt versus Junction Temperature at 0.8 Amps RMS

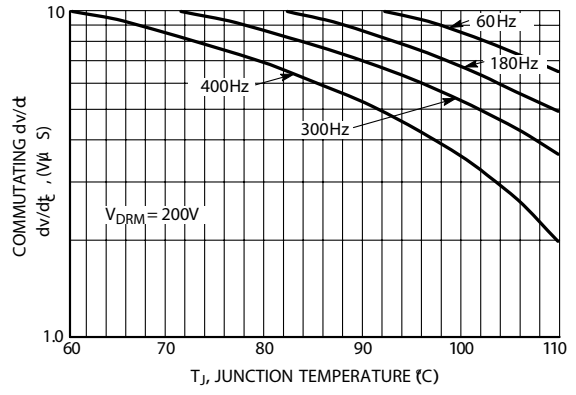


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Figure 13. Exponential Static dv/dt versus Gate – Main Terminal 1 Resistance

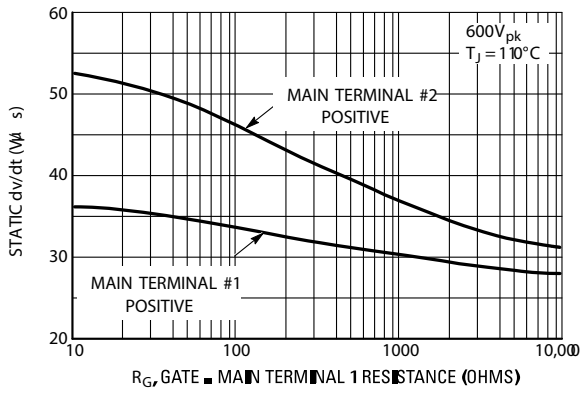


Figure 14. Typical Gate Trigger Current Variation

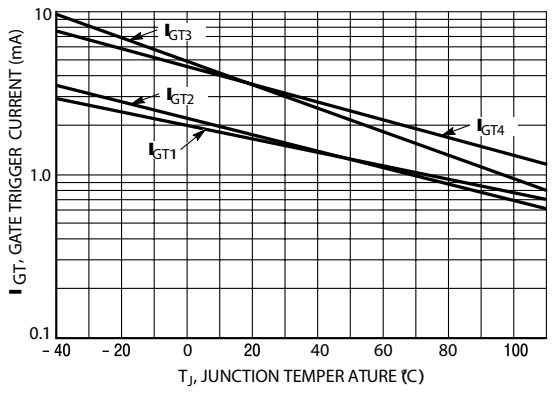


Figure 15. Typical Holding Current Variation

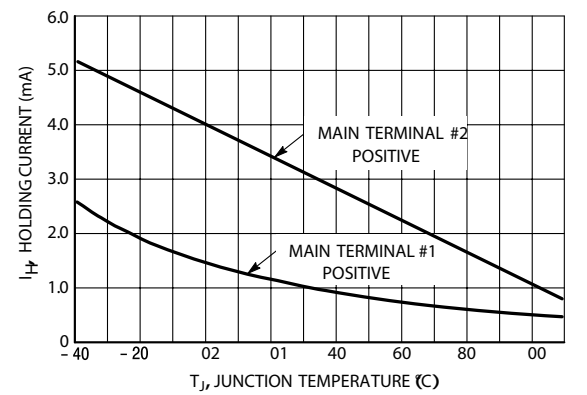
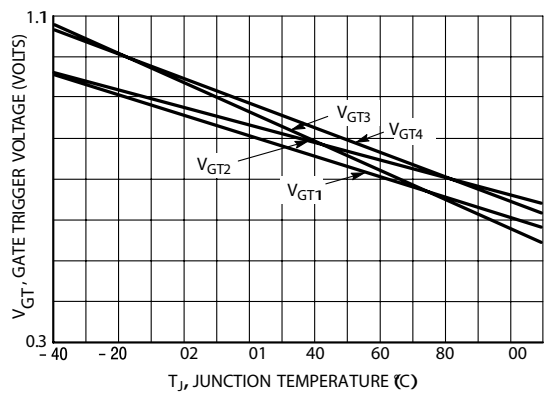


Figure 16. Gate Trigger Voltage Variation



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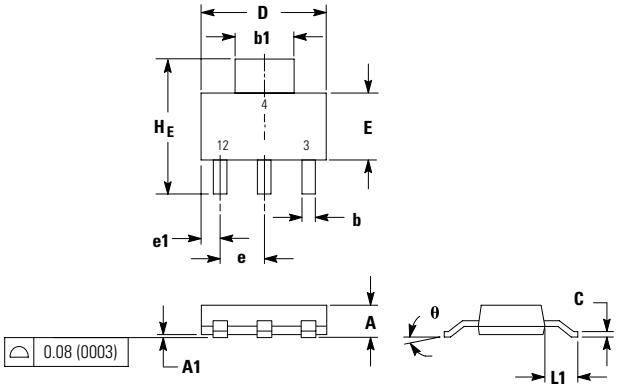
Thyristors

Surface Mount – 200V - 600V > MAC08BT1, MAC08MT1

Dimensions

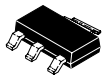


Dim	Inches			Millimeters		
	Min	Nom	Max	Min	Nom	Max
A	---	---	0.071	---	---	1.80
A1	0.001	0.003	0.005	0.02	0.07	0.13
b	0.026	0.030	0.033	0.66	0.75	0.84
b1	0.114	0.118	0.122	2.90	3.00	3.10
c	0.009	0.011	0.014	0.23	0.29	0.35
D	0.260	0.260	0.264	6.60	6.60	6.71
E	0.130	0.138	0.146	3.30	3.50	3.70
e	---	0.091	---	---	2.30	---
e1	0.030	0.037	0.045	0.75	0.95	1.15
L1	0.059	0.069	0.079	1.50	1.75	2.00
HE	0.268	0.276	0.283	6.80	7.00	7.20
ø	0°	---	10°	0°	---	10°

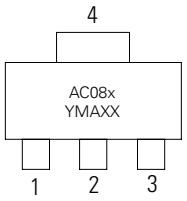
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

Pin Assignment	
1	Main Terminal 1
2	Main Terminal 2
3	Gate
4	Main Terminal 2

Part Marking System

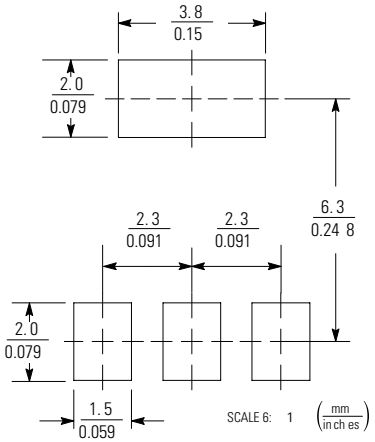


SOT-223
Case 318E
Style 11



AC08X	=Device Code
x	=D, M, or N
Y	=Year
M	=Month
A	=Assembly Site
XX	=Lot Serial Code
G	=Pb-Free Package

Soldering Footprint



Ordering Information

Device	Package Type	Shipping
MAC08BT1	SOT–223	1000 / Tape & Reel
MAC08BT1G	SOT–223 (Pb–Free)	1000 / Tape & Reel
MAC08MT1	SOT–223	1000 / Tape & Reel
MAC08MT1G	SOT–223 (Pb–Free)	1000 / Tape & Reel

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- Помощь Конструкторского Отдела и консультации квалифицированных инженеров;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Поставка электронных компонентов под контролем ВП;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
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- Поставка специализированных компонентов военного и аэрокосмического уровня качества (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Actel, Aeroflex, Peregrine, VPT, Syfer, Eurofarad, Texas Instruments, MS Kennedy, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

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